TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74VHC165F,TC74VHC165FN,TC74VHC165FT,TC74VHC165FK

8-Bit Shift Register (P-IN, S-OUT)

The TC74VHC165 is an advanced high speed CMOS 8-BIT PARALLEL/SERIAL-IN, SERIAL-OUT SHIFT REGISTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of parallel-in or serial-in, serial-out 8-bit shift register with a gated clock input. When the SHIFT/ $\overline{\text{LOAD}}$  input is held high, the serial data input is enabled and the eight frip-frops perform serial shifting with each clock pulse.

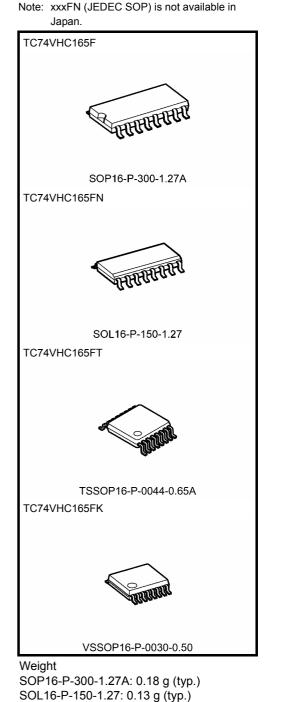
When the SHIFT/ $\overline{\text{LOAD}}$  input is held low, the parallel data is loaded synchronously into the register at positive going transition of the clock pulse.

The CK-INH input should be shifted high only when the CK input is held high.

An Input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### Features

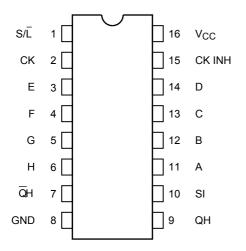
- High speed:  $f_{max} = 150 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \pmod{at Ta} = 25^{\circ}C$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 V to 5.5 V
- Pin and function compatible with 74ALS165



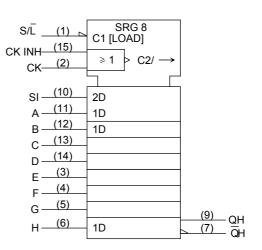
TSSOP16-P-0044-0.65A: 0.06 g (typ.) VSSOP16-P-0030-0.50: 0.02 g (typ.)

# <u>TOSHIBA</u>

#### **Pin Assignment**



### **IEC Logic Symbol**



#### **Truth Table**

Inputs						Internal Outputs		puts
SHIFT/ LOAD	CK INH	СК	SERIAL IN	PARALLEL A······H	QA	QB	QH	QH
L	Х	Х	Х	a·····h	а	b	h	ĥ
Н	L		Н	Х	Н	QAn	QGn	$\overline{Q}G_n$
Н	L		L	Х	L	QAn	QGn	$\overline{Q}G_n$
Н		L	Н	Х	H QA <sub>n</sub>		QGn	$\overline{Q}G_n$
Н		L	L	Х	L QA <sub>n</sub>		QGn	$\overline{Q}G_n$
Н	Х	Н	Х	Х	No Change			
Н	Н	Х	Х	Х	No Change			

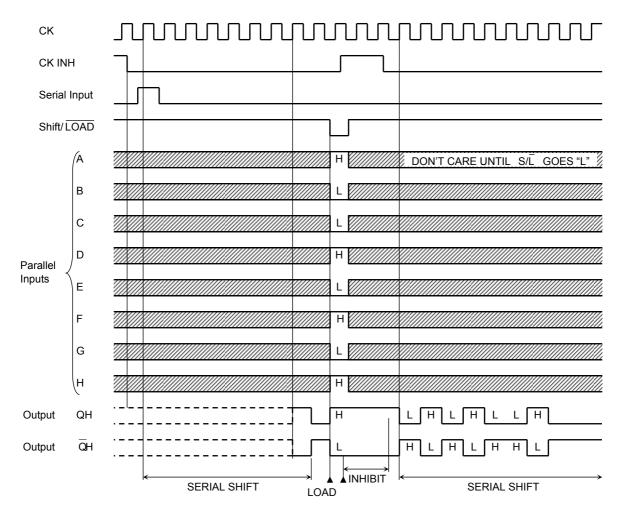
#### X: Don't care

a.....h: The level of steady state input voltage at inputs A through H respectively

 $QA_n$  to  $QG_n$ : The level of QA to QG, respectively, before the most recent positive transition of the CK.

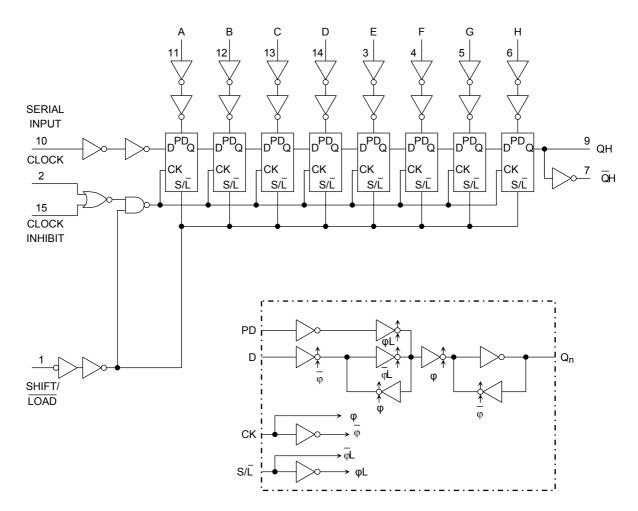
# TOSHIBA

### **Timing Chart**



# <u>TOSHIBA</u>

#### System Diagram



#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	lıĸ	-20	mA
Output diode current	lок	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 $\pm$ 0.3 V)	ns/V	
	uvuv	0 to 20 (V_{CC} = 5 $\pm$ 0.5 V)	115/ V	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		- Unit
Characteristics	Gymbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	VIH	—			1.50 V <sub>CC</sub> × 0.7		_	1.50 V <sub>CC</sub> × 0.7		V
Low-level input voltage	VIL	_		2.0 3.0 to 5.5	_	_	0.50 V <sub>CC</sub> × 0.3	_	0.50 V <sub>CC</sub> × 0.3	V
High-level output voltage	Vон	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	A 3.0 2.9 3.0 -			1.9 2.9 4.4		V	
			I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -8 mA	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or	l <sub>OL</sub> = 50 μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
	VIL	VIL	I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA	3.0 4.5		_	0.36 0.36		0.44 0.44	
Input leakage current	IIN	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_		±0.1		±1.0	μA
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		5.5			4.0		40.0	μA

### Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol Test Condition			Ta = 25°C	Ta = -40 to 85°C	Unit	
			$V_{CC}(V)$	Limit	Limit		
Minimum pulse width	t <sub>w (L)</sub>		$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0	20	
(CK, CK INH)	t <sub>w (H)</sub>		$5.0\pm0.5$	4.0	4.0	ns	
Minimum pulse width			$\textbf{3.3}\pm\textbf{0.3}$	7.5	9.0		
(S/L)	t <sub>w (L)</sub>		$5.0\pm0.5$	5.0	6.0	ns	
Minimum set-up time			$\textbf{3.3}\pm\textbf{0.3}$	7.5	8.5		
(PI- S/L )	ts		$5.0\pm0.5$	5.0	5.0	ns	
Minimum set-up time			$\textbf{3.3}\pm\textbf{0.3}$	5.0	6.0		
(SI-CK, CK INH)	t <sub>s</sub>		$5.0\pm0.5$	4.0	4.0	ns	
Minimum set-up time			$\textbf{3.3}\pm\textbf{0.3}$	5.0	6.0		
(S/L-CK, CK INH)	t <sub>s</sub>		$5.0\pm0.5$	4.0	4.0	ns	
Minimum hold time			$\textbf{3.3}\pm\textbf{0.3}$	0.5	0.5		
(PI-S/L)	t <sub>h</sub>		$5.0 \pm 0.5$	1.0	1.0	ns	
Minimum hold time			$\textbf{3.3}\pm\textbf{0.3}$	0.0	0.0		
(SI-CK, CK INH)	t <sub>h</sub>		$5.0 \pm 0.5$	0.5	0.5	ns	
Minimum hold time	4		$\textbf{3.3}\pm\textbf{0.3}$	0.0	0.0	20	
(S/L-CK, CK INH)	t <sub>h</sub>	—	$5.0\pm0.5$	0.5	0.5	ns	
Minimum removal time			22102	5.0	5.0		
(CK INH-CK)	t <sub>rem</sub>	—	3.3 ± 0.3	5.0	5.0	ns	
(CK-CK INH)			$5.0\pm0.5$	3.5	3.5		

#### AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

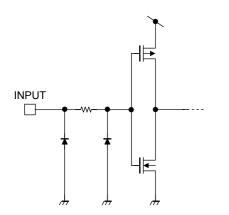
Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,	V <sub>CC</sub> (V)		C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
			$3.3\pm0.3$	15	_	9.9	15.4	1.0	18.0	
Propagation delay time	t <sub>pLH</sub>		5.5 ± 0.5	50	_	12.4	18.9	1.0	21.5	ns
$(CK, CK INH-QH, \overline{Q}H)$	t <sub>pHL</sub>		5.0 ± 0.5	15	_	6.6	9.9	1.0	11.5	115
			$5.0 \pm 0.5$	50	_	8.1	11.9	1.0	13.5	
			$3.3\pm0.3$	15	_	9.9	15.8	1.0	18.5	
Propagation delay time	t <sub>pLH</sub>		$3.3 \pm 0.3$	50	_	12.4	19.3	1.0	22.0	
(S/L-QH, QH)	t <sub>pHL</sub>	_	5.0 ± 0.5	15	_	6.7	9.9	1.0	11.5	ns
			$5.0 \pm 0.5$	50	_	8.2	11.9	1.0	13.5	
			3.3 ± 0.3	15	_	9.2	14.1	1.0	16.5	
Propagation delay time	t <sub>pLH</sub>		$5.5 \pm 0.5$	50	_	11.7	17.6	1.0	20.0	ns
(H-QH, QH)	t <sub>pHL</sub>	_	5.0 ± 0.5	15	_	5.9	9.0	1.0	10.5	115
			0.0 ± 0.0	50	_	7.4	11.0	1.0	12.5	
			$3.3\pm0.3$	15	65	85	_	55	_	
Maximum clock frequency	f		5.5 ± 0.5	50	60	105	_	50	_	MHz
Maximum clock frequency	f <sub>max</sub>	_	$5.0 \pm 0.5$	15	110	150	_	90	_	
			$5.0 \pm 0.0$	50	95	130	_	85	_	
Input capacitance	C <sub>IN</sub>		_		_	4	10		10	pF
Power dissipation capacitance	C <sub>PD</sub>			(Note)		50		_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### Input Equivalent Circuit

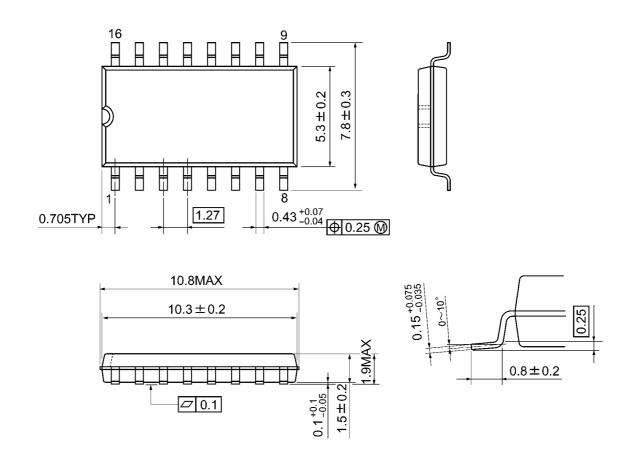




#### **Package Dimensions**

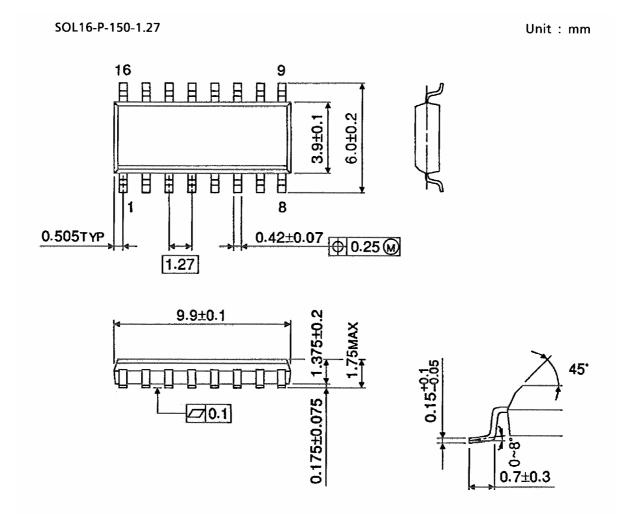
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

#### Package Dimensions (Note)



Note: This package is not available in Japan.

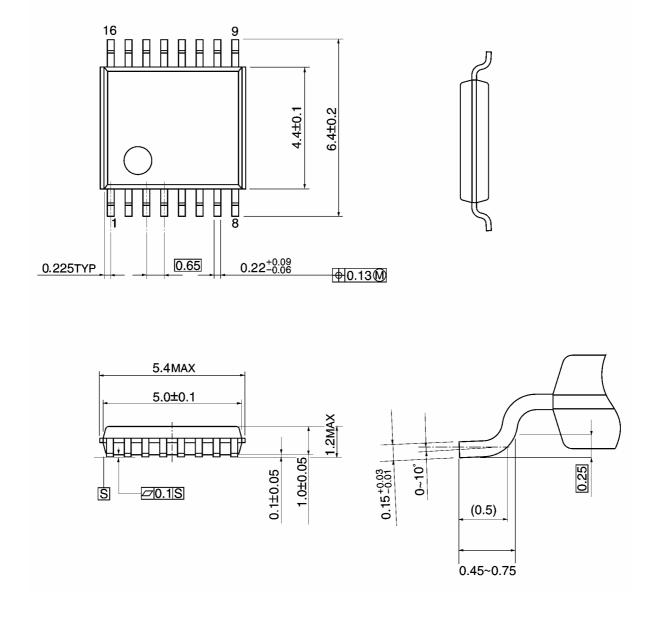
Weight: 0.13 g (typ.)

## **TOSHIBA**

### Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



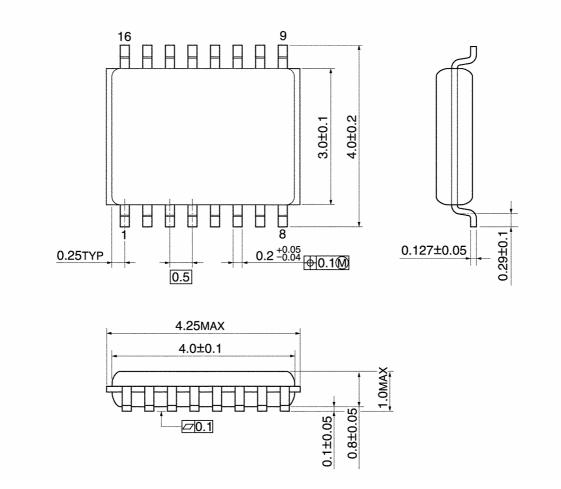
Weight: 0.06 g (typ.)

**TOSHIBA** 

#### **Package Dimensions**

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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